NSN 5962-01-039-5043

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View Online at https://aerobasegroup.com/nsn/5962-01-039-5043

Overall Height:
Between 0.275 inches and 0.390 inches
Body Length:
Between 1.235 inches and 1.290 inches
Body Width:
0.560 inches
Body Height:
Between 0.130 inches and 0.170 inches
Maximum Power Dissipation Rating:
165.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and bipolar and 3-state output and programmable and w/strobe
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Capitance Rating Per Characteristic:
5.00 input picofarads and 8.00 output picofarads
Memory Device Type:
Prom
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<u></u>
Demilitarization:

Yes - demil/mli

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